

Ultra-low Power, RRIO, 1.8V, Push-Pull Output Comparators

Features

- 46uA (Typ) Low Power Consumption
- Fast, 70ns Propagation Delay
- Single-Supply Operation from +1.8V ~ +5.5V
- Low Offset Voltage: 3mV (Max)
- Rail-to-Rail Input and Output
- CMOS/TTL-Compatible Output
- Internal Hysteresis for Clean Switching
- No Phase Reversal for Overdriven Inputs
- Operating Temperature: -40°C ~ +85°C
- Small Package:

HGV331 Available in SOT-23-5 and SC70-5 Packages

HGV332 Available in SOP-8、DFN and MSOP-8 Packages



Ordering Information

DEVICE	Package Type	MARKING	Packing	Packing Qty
HGV331M5/TR	SOT-23-5	V331	REEL	3000/reel
HGV331M7/TR	SC70-5(SOT-353)	V331	REEL	3000/reel
HGV332M/TR	SOP-8	HGV332	REEL	2500/reel
HGV332MM/TR	MSOP-8	V332	REEL	3000/reel
HGV332DQ3/TR	DFN-8 3*3	V332	REEL	5000/reel

General Description

The HGV331 is low-power, high-speed comparator with internal hysteresis, optimized for systems powered from a 3V or 5V supply. The device features high-speed response, low-power consumption, low offset voltage, and rail-to-rail input and output range.

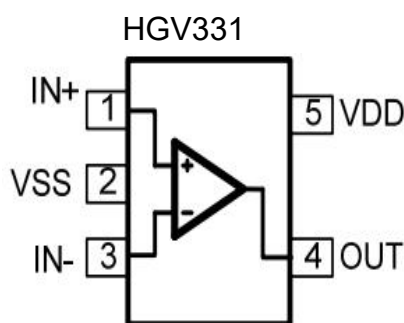
Propagation delay is 70ns (100mV overdrive), while supply current is 46uA per comparator. The internal input hysteresis eliminates output switching due to internal input noise voltage. The maximum input offset voltage is 3mV, and the operating range is from 1.8V to 5.5V.

All devices are specified for the temperature range of -40°C to +85°C. The HGV331 single is available in Green SC70-5 and SOT-23-5 packages. The HGV332 dual is available in Green SOP-8, DFN and MSOP-8 packages.

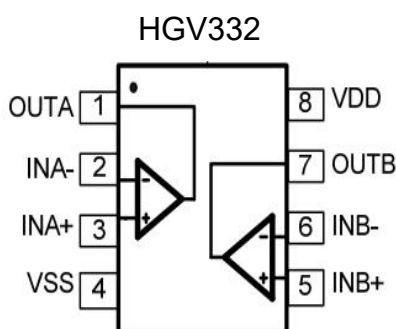
Applications

- Alarm and Monitoring Circuits
- Peak and Zero-crossing Detectors
- Logic Level Shifting or Translation
- RC Timers
- Window Comparators
- IR Receivers
- Portable Systems

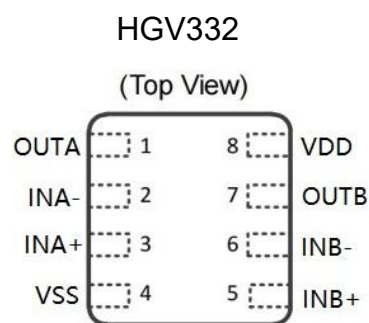
Pin Configuration



SOT-23-5/SC70-5



SOP-8/MSOP-8



DFN-8 3*3

Absolute Maximum Ratings

Condition		Min	Max
Power Supply Voltage (VDD to Vss)		-0.5V	+7.5V
Analog Input Voltage (IN+ or IN-)		Vss-0.5V	VDD+0.5V
PDB Input Voltage		Vss-0.5V	+7V
Operating Temperature Range		-40°C	+85°C
Junction Temperature		-	+160°C
Storage Temperature Range		-55°C	+150°C
Lead Temperature (soldering, 10sec)		-	+260°C
Package Thermal Resistance (TA=+25°C)	SOP-8, 8JA	-	125°C/W
	MSOP-8, 8JA	-	216°C/W
	SOT-23-5, 8JA	-	190°C/W
	SC70-5, 8JA	-	333°C/W
ESD Susceptibility	HBM	-	4KV
	MM	-	300V

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability

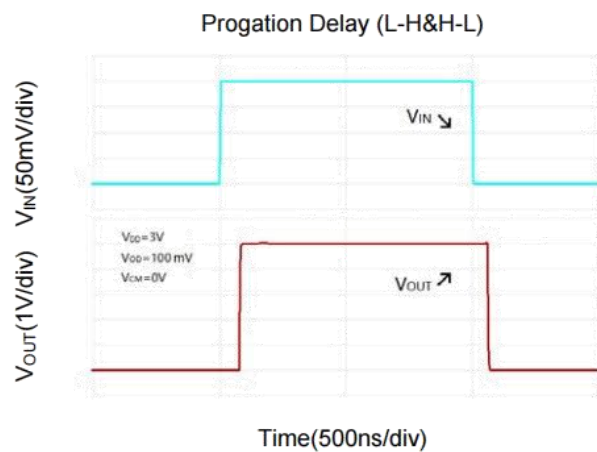
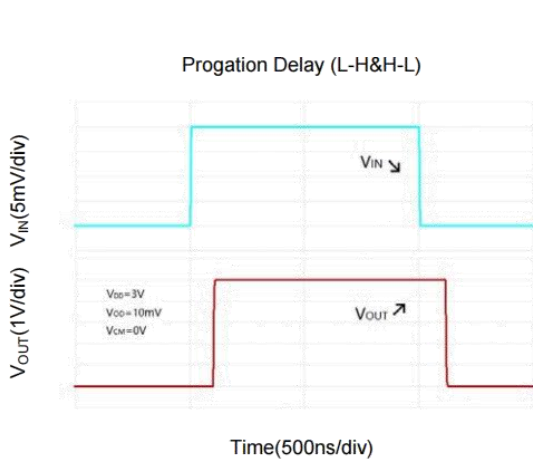
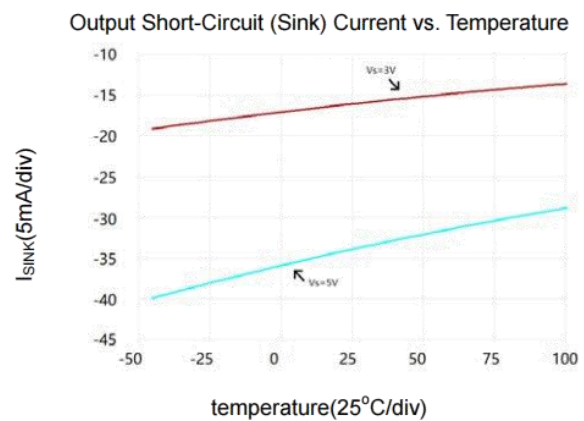
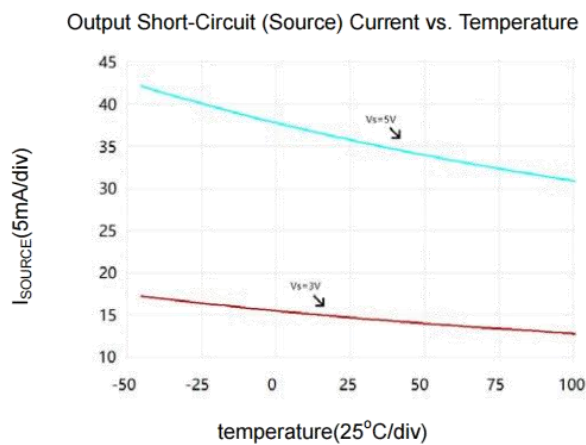
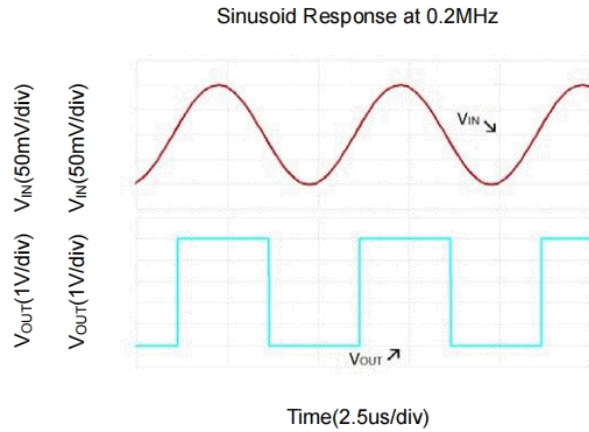
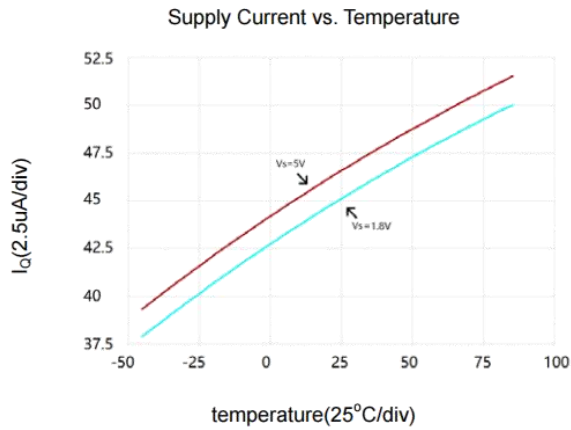
Electrical Characteristics

(At $V_S = +5V$, $V_{CM} = 0V$, $C_L = 15pF$, and $T_A = +25^{\circ}C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS				
			TYP	MIN	MAX	UNITS
INPUT CHARACTERISTICS						
Input Offset Voltage	VOS	VCM = 0V	0.5		3	mV
Input Bias Current	IB		6			pA
Input Offset Current	IOS		4			pA
Input Hysteresis	Vhys		6			mV
Common-Mode Voltage Range	VCM	VS = 5.5V	-0.1 to +5.6			V
Common-Mode Rejection Ratio	CMRR	VS = 5V, VCM = 0V to 5V	70	50		dB
OUTPUT CHARACTERISTICS						
Output Voltage Swing from Rail	VOH	Vs=5V, IO = 1mA	Vs - 0.05		Vs - 0.3	V
	VOL		57		300	mV
Output Short-Circuit Current	ISOURCE	VS = 5V, Out to VS/2	35			mA
	ISINK		33			
POWER SUPPLY						
Operating Voltage Range			1.8			V
			5.5			V
Power Supply Rejection Ratio	PSRR	VS = +1.6V to +5.5V, VCM = 0V	75	60		dB
Quiescent Current / Comparator	IQ		46			uA
DYNAMIC PERFORMANCE (CL = 15pF)						
Propagation Delay (Low to High)	TdLH	VS = 3V, Overdrive = 10mV	98.6			ns
		VS = 3V, Overdrive = 100mV	77.5			ns
Propagation Delay (High to Low)	TdHL	VS = 3V, Overdrive = 10mV	114.7			ns
		VS = 3V, Overdrive = 100mV	59.4			ns
Rise Time	Tr	VS = 3V, Overdrive = 10mV	5			ns
		VS = 3V, Overdrive = 100mV	5			ns
Fall Time	Tf	VS = 3V, Overdrive = 10mV	5			ns
		VS = 3V, Overdrive = 100mV	5			ns

Typical Performance characteristics

At TA=+25°C, VS=+5V, and CL=15pF, unless otherwise noted.



Application Note

Size

HGV331 comparator is low-power, high-speed and suitable for a wide range of general-purpose applications. The small footprints of the HGV331 package saves space on printed circuit boards and enable the design of smaller electronic products. The HGV331 interfaces directly to CMOS and TTL logics.

Power Supply Bypassing and Board Layout

HGV331 operates from a single 1.8V to 5.5V supply or dual $\pm 0.9V$ to $\pm 2.75V$ supplies. For best performance, a $0.1\mu F$ ceramic capacitor should be placed close to the VDD pin in single supply operation. For dual supply operation, both VDD and VSS supplies should be bypassed to ground with separate $0.1\mu F$ ceramic capacitors.

Low Supply Current

The low supply current (typical $46\mu A$ per channel) of HGV331 will help to maximize battery life. They are ideal for battery powered systems.

Operating Voltage

HGV331 operates under wide input supply voltage (1.8V to 5.5V). In addition, all temperature specifications apply from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime

Rail-to-Rail Input

The input common-mode range of HGV331 extends 100mV beyond the supply rails ($V_{SS}-0.1V$ to $V_{DD}+0.1V$). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Internal Hysteresis

Because of noise or undesired parasitic feedback, high-speed comparators oscillate in the linear region. Oscillation tends to occur when the voltage on one input is at or equal to the voltage on the other input. The LM806 family eliminates this undesired oscillation by integrating an internal hysteresis of 6mV .

The hysteresis in a comparator creates two trip points: one for the rising input voltage and one for the falling input voltage (Figure 2). The difference between two trip points is the hysteresis, while the average of two trip points is the offset voltage. When the comparator's input voltages are equal, the hysteresis effectively causes one comparator input voltage to move quickly past the other, thus taking the input out of the region where oscillation occurs.

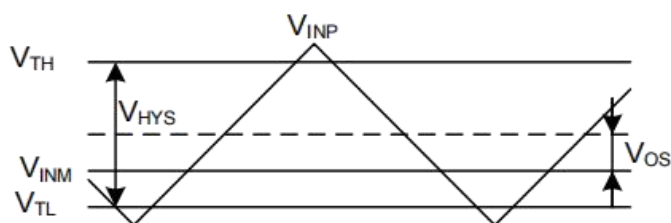


Figure 2. Comparator's hysteresis and offset

External Hysteresis

Greater flexibility in selecting hysteresis is achieved by using external resistors. Hysteresis reduces output chattering when one input is slowly moving past the other.

Non-Inverting Comparator with Hysteresis

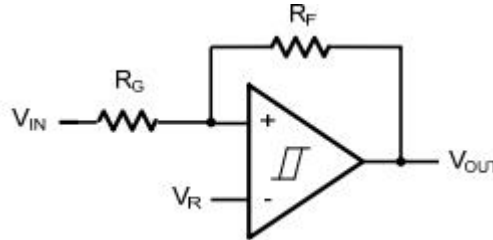


Figure 3. Non-Inverting Comparator with Hysteresis

A non-inverting comparator with hysteresis requires a two-resistor network, as shown in Figure 3 and a voltage reference (V_R) at the inverting input.

$$V_{TH} = \frac{R_G + R_F}{R_F} \times V_R$$

$$V_{TL} = \frac{R_G + R_F}{R_F} \times V_R - \frac{R_G}{R_F} \times V_{DD}$$

$$V_{HYS} = \frac{R_G}{R_F} \times V_{DD}$$

Inverting Comparator with Hysteresis

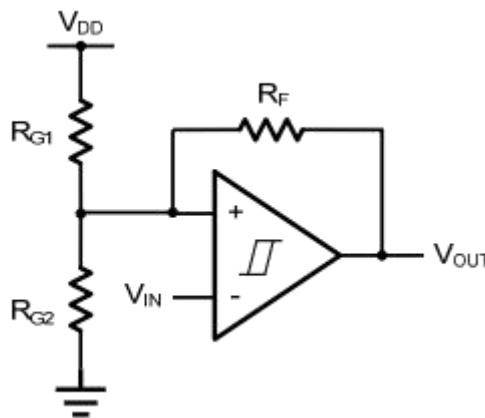


Figure 4. Inverting Comparator with Hysteresis

$$V_{TH} = \frac{R_{G2}}{R_{G1} \parallel R_F + R_{G2}} \times V_{DD}$$

$$V_{TL} = \frac{R_{G2} \parallel R_F}{R_{G2} \parallel R_F + R_{G1}} \times V_{DD}$$

$$V_{HYS} = \frac{R_{G1} \parallel R_{G2}}{R_{G1} \parallel R_{G2} + R_F} \times V_{DD}$$

Typical Application Circuits

Line Receiver

A Line Receiver using HGV331 is shown in Figure 5. Resistors R_{G1} and R_{G2} set the bias point at the comparator's inverting input. R_{IN} should be same as $R_{G1}||R_{G2}$ to get a better match. HGV331 detects the voltage of the Coax Line, and outputs logic high or logic low quickly with no glitch.

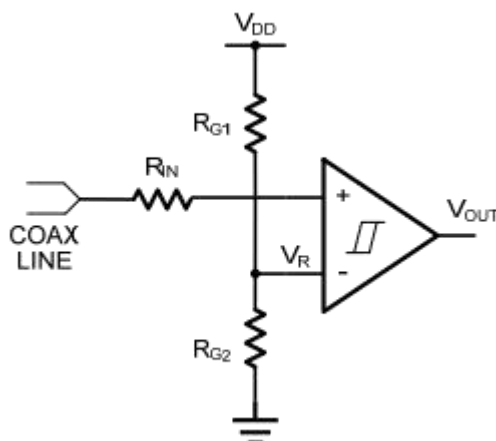


Figure 5. Line Receiver

IR Receiver

HGV331 is an ideal candidate to be used as an infrared receiver shown in Figure 6. The infrared photo diode creates a current relative to the amount of infrared light present. The current creates a voltage across R_{IN} . When this voltage level cross the voltage applied by the voltage divider to the inverting input, the output transitions. Optional R_F provides additional hysteresis for noise immunity.

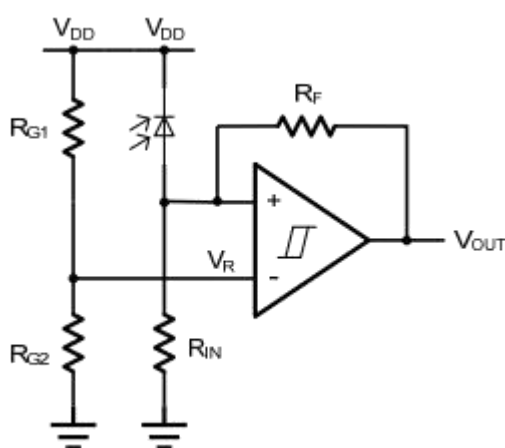


Figure 6. IR Receiver

Oscillator

A oscillator using HGV331 is shown in Figure 7. Resistors RG1 and RG2 set the bias point at the comparator's inverting input.

The period of oscillator is set by the time constant of RC and CIN. The maximum frequency is limited by the large signal propagation delay of the comparator. HGV331 is low propagation delay guarantees the high frequency oscillation.

If $R_{G1}=R_{G2}=R_F$, then the frequency of the oscillator is:

$$F_{osc} = \frac{1}{2 \times 1n2 \times RC \times C_{IN}}$$

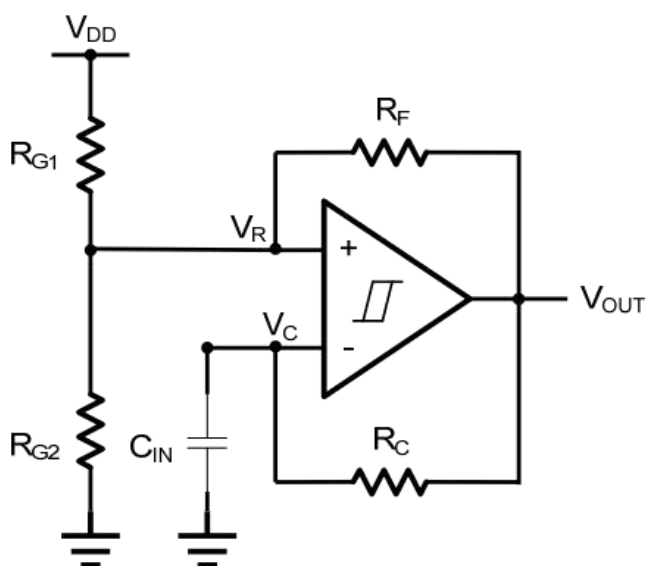
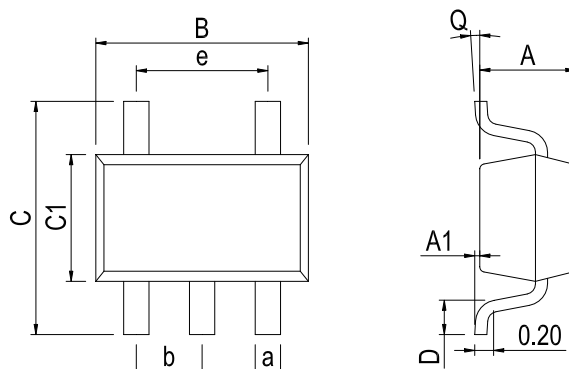


Figure 7. Oscillator

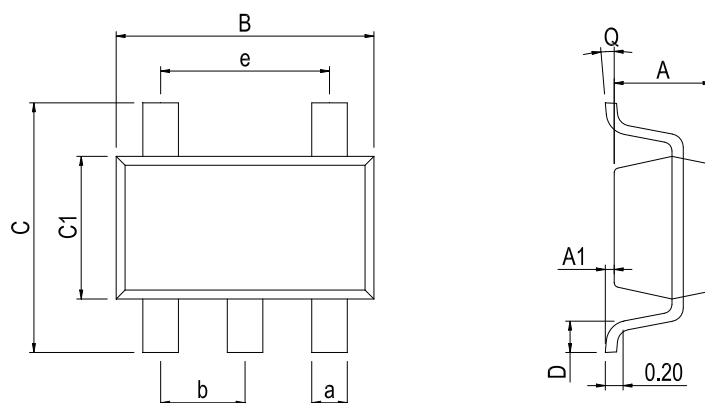
Physical Dimensions

SOT-23-5



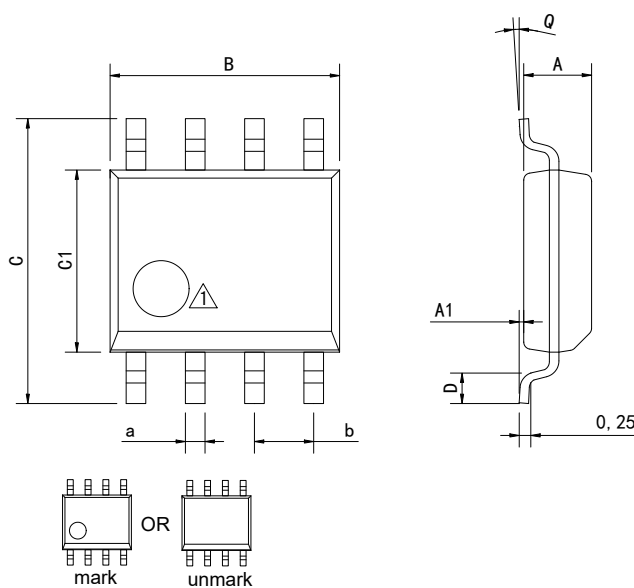
Dimensions In Millimeters(SOT-23-5)										
Symbol:	A	A1	B	C	C1	D	Q	a	b	e
Min:	1.00	0.00	2.82	2.65	1.50	0.30	0°	0.30	0.95 BSC	1.90 BSC
Max:	1.15	0.15	3.02	2.95	1.70	0.60	8°	0.50		

SC70-5



Dimensions In Millimeters(SC70-5)										
Symbol:	A	A1	B	C	C1	D	Q	a	b	e
Min:	0.90	0.00	2.00	2.15	1.15	0.26	0°	0.15	0.65 BSC	1.30 BSC
Max:	1.00	0.15	2.20	2.45	1.35	0.46	8°	0.35		

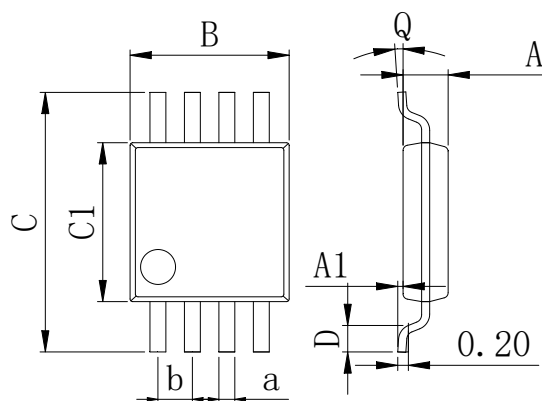
SOP-8



① Package top mark may be in lower left corner or unmark

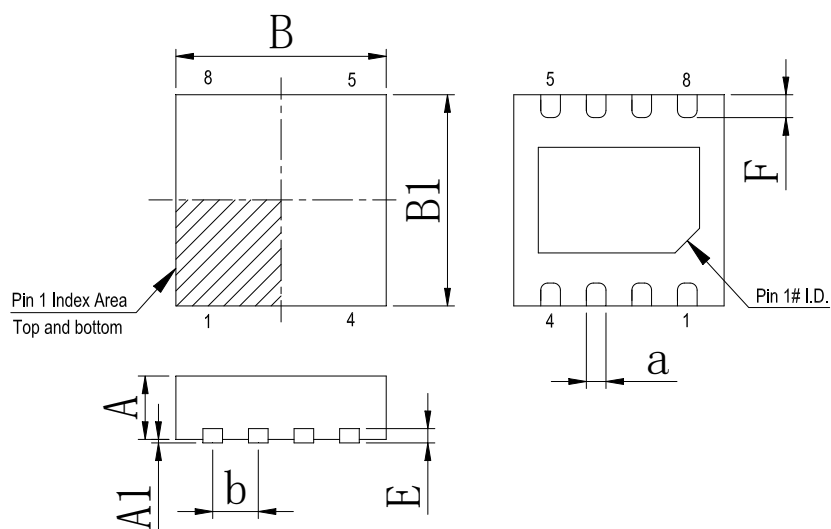
Dimensions In Millimeters(SOP-8)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	

MSOP-8



Dimensions In Millimeters(MSOP-8)									
Symbol:	A	A1	B	C	C1	D	Q	a	b
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	

DFN-8 3*3



Dimensions In Millimeters(DFN-8 3*3)								
Symbol:	A	A1	B	B1	E	F	a	b
Min:	0.85	0.00	2.90	2.90	0.20	0.30	0.20	0.65 BSC
Max:	0.95	0.05	3.10	3.10	0.25	0.50	0.34	

Revision History

REVISION NUMBER	DATE	REVISION	PAGE
V1.0	2015-9	New	1-14
V1.1	2016-10	Update encapsulation type、Update SC70-5 Physical Dimensions	1、 10
V1.2	2024-11	Update SOT-23-5 Physical dimension、Update Lead Temperature	3、 10
V1.3	2025-12	Update important statements、Update SOP-8 Dimension drawing	11、 14

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